

# 2N4117, 2N4117A, 2N4118, 2N4118A, 2N4119, 2N4119A

## N-Channel Silicon Junction Field-Effect Transistor

- Audio Amplifiers
- Ultra-High Input Impedance Amplifiers

### Absolute maximum ratings at $T_A = 25^\circ\text{C}$

Reverse Gate Source & Reverse Gate Drain Voltage	- 40 V
Continuous Forward Gate Current	50 mA
Continuous Device Power Dissipation	300 mW
Power Derating (to 175°C)	2 mW/°C

At 25°C free air temperature:  
Static Electrical Characteristics

		2N4117 2N4117A		2N4118 2N4118A		2N4119 2N4119A		Process NJ01	
		Min	Max	Min	Max	Min	Max	Unit	Test Conditions
Gate Source Breakdown Voltage	$V_{(BR)GSS}$	- 40		- 40		- 40		V	$I_G = - 1\mu\text{A}, V_{DS} = \emptyset\text{V}$
Gate Reverse Current 2N4117, 2N4118, 2N4119 2N4117A, 2N4118A, 2N4119A	$I_{GSS}$		- 10		- 10		- 10	pA	$V_{GS} = - 20\text{V}, V_{DS} = \emptyset\text{V}$
			- 1		- 1		- 1	pA	$V_{GS} = - 20\text{V}, V_{DS} = \emptyset\text{V}$
Gate Source Cutoff Voltage	$V_{GS(OFF)}$	- 0.6	- 1.8	- 1	- 3	- 2	- 6	V	$V_{DS} = 10\text{V}, I_D = 1\text{ nA}$
Drain Saturation Current (Pulsed) 2N4117, 2N4118, 2N4119 2N4117A, 2N4118A, 2N4119A	$I_{GSS}$	0.03	0.09	0.08	0.24	0.2	0.6	mA	$V_{DS} = 10\text{V}, V_{GS} = \emptyset\text{V}$
		0.015	0.09	0.08	0.24	0.2	0.6	mA	$V_{DS} = 10\text{V}, V_{GS} = \emptyset\text{V}$

### Dynamic Electrical Characteristics

Common Source Forward Transconductance	$g_{fs}$	70	210	80	250	100	330	$\mu\text{S}$	$V_{DS} = 10\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1\text{ kHz}$
Common Source Output Conductance	$g_{os}$		3		5		10	$\mu\text{S}$	$V_{DS} = 10\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1\text{ kHz}$
Common Source Input Capacitance	$C_{iss}$		3		3		3	pF	$V_{DS} = 10\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1\text{ MHz}$
Common Source Reverse Transfer Capacitance	$C_{rss}$		1.5		1.5		1.5	pF	$V_{DS} = 10\text{V}, V_{GS} = \emptyset\text{V}$	$f = 1\text{ MHz}$

### TO-72 Package

Dimensions in Inches (mm)

### Pin Configuration

1 Source, 2 Drain, 3 Gate, 4 Case

